NSN 5961-01-257-7507

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-257-7507 **Inclosure Material:** Glass **Overall Length:** 2.750 inches **Terminal Length:** 1.2925 inches **Overall Diameter:** 0.110 inches **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.030 inches and 0.032 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 working peak reverse voltage and 200.0 repetitive peak reverse voltage and 200.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 1.00 amperes forward current, average and 50.00 amperes forward current, average preset **Power Rating Per Characteristic:** 38.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release6218 professional/industrial association standard Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0